

## Ultra-Low Noise Precision Operational Amplifier

March 1993

### Features

- High Speed ..... 10V/ $\mu$ s
- Wide Unity Gain Bandwidth ..... 8.5MHz
- Low Noise ..... 3nV/ $\sqrt{\text{Hz}}$  at 1kHz
- Low  $V_{OS}$  ..... 10 $\mu$ V
- High CMRR ..... 126dB
- High Gain ..... 1800V/mV

### Applications

- High Speed Signal Conditioners
- Wide Bandwidth Instrumentation Amplifiers
- Low Level Transducer Amplifiers
- Fast, Low Level Voltage Comparators
- Highest Quality Audio Preamplifiers
- Pulse/RF Amplifiers

### Description

The HA-5127 monolithic operational amplifier features an unparalleled combination of precision DC and wideband high speed characteristics. Utilizing the Harris D. I. technology and advanced processing techniques, this unique design unites low noise (3nV/ $\sqrt{\text{Hz}}$ ) precision instrumentation performance with high speed (10V/ $\mu$ s) wideband capability.

This amplifier's impressive list of features include low  $V_{OS}$  (10 $\mu$ V), wide unity gain-bandwidth (8.5MHz), high open loop gain (1800V/mV), and high CMRR (126dB). Additionally, this flexible device operates over a wide supply range ( $\pm 5$ V to  $\pm 20$ V) while consuming only 140mW of power.

Using the HA-5127 allows designers to minimize errors while maximizing speed and bandwidth.

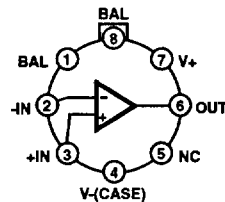
This device is ideally suited for low level transducer signal amplifier circuits. Other applications which can utilize the HA-5127's qualities include instrumentation amplifiers, pulse amplifiers, audio preamplifiers, and signal conditioning circuits. This device can easily be used as a design enhancement by directly replacing the 725, OP25, OP06, OP07, OP27 and OP37. For the military grade product, refer to the HA-5127/883 data sheet.

### Ordering Information

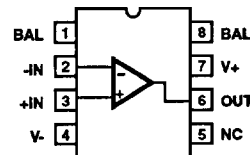
PART NUMBER	TEMPERATURE RANGE	PACKAGE
HA2-5127-2	-55°C to +125°C	8 Pin CAN
HA2-5127-5	0°C to +75°C	8 Pin CAN
HA2-5127A-2	-55°C to +125°C	8 Pin CAN
HA2-5127A-5	0°C to +75°C	8 Pin CAN
HA3-5127A-5	0°C to +75°C	8 Lead Plastic DIP
HA7-5127-2	-55°C to +125°C	8 Lead Ceramic DIP
HA7-5127-5	0°C to +75°C	8 Lead Ceramic DIP
HA7-5127A-2	-55°C to +125°C	8 Lead Ceramic DIP
HA7-5127A-5	0°C to +75°C	8 Lead Ceramic DIP
HA9P5127-5	0°C to +75°C	8 Lead SOIC

### Pinouts

HA-5127  
(TO-99 METAL CAN)  
TOP VIEW



HA-5127  
(PDIP, CDIP, SOIC)  
TOP VIEW



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper I.C. Handling Procedures.

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File Number 2906.1

## Specifications HA-5127, HA-5127A

### Absolute Maximum Ratings (Note 1)

$T_A = +25^\circ\text{C}$ Unless Otherwise Stated	
Supply Voltage Between $V_+$ and $V_-$ Terminals	44V
Differential Input Voltage (Note 2)	0.7V
Output Current	Full Short Circuit Protection
Junction Temperature (Note 13)	+175°C
Junction Temperature (Plastic Package)	+150°C
Lead Temperature (Soldering 10 Sec.)	+300°C

### Operating Conditions

Operating Temperature Range	
HA-5127/27A-2	$-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$
HA5127/27A-5	$0^\circ\text{C} \leq T_A \leq +75^\circ\text{C}$
Storage Temperature Range	$-65^\circ\text{C} \leq T_A \leq +150^\circ\text{C}$

**CAUTION:** Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### Electrical Specifications $V_+ = 15\text{V}$ , $V_- = -15\text{V}$ , $C_L < 50\text{pF}$ , $R_S < 100\Omega$

PARAMETER	TEMP	HA-5127A			HA-5127			UNITS	
		MIN	TYP	MAX	MIN	TYP	MAX		
<b>INPUT CHARACTERISTICS</b>									
Offset Voltage	+25°C	-	10	25	-	30	100	$\mu\text{V}$	
	Full	-	30	60	-	70	300	$\mu\text{V}$	
Average Offset Voltage Drift	Full	-	0.2	0.6	-	0.4	1.8	$\mu\text{V}/^\circ\text{C}$	
Bias Current	+25°C	-	$\pm 10$	$\pm 40$	-	$\pm 15$	$\pm 80$	nA	
	Full	-	$\pm 20$	$\pm 60$	-	$\pm 35$	$\pm 150$	nA	
Offset Current	+25°C	-	7	35	-	12	75	nA	
	Full	-	15	50	-	30	135	nA	
Common Mode Range	Full	$\pm 10.3$	$\pm 11.5$	-	$\pm 10.3$	$\pm 11.5$	-	V	
Differential Input Resistance (Note 3)	+25°C	1.5	6	-	0.8	4	-	M $\Omega$	
Input Noise Voltage 0.1Hz to 10Hz (Note 4)	+25°C	-	0.08	0.18	-	0.09	0.25	$\mu\text{V}_{\text{P-P}}$	
Input Noise Voltage Density (Note 5)	+25°C	$f = 10\text{Hz}$	-	3.5	5.5	-	3.8	8.0	$\text{nV}/\sqrt{\text{Hz}}$
		$f = 100\text{Hz}$	-	3.1	4.5	-	3.3	5.6	$\text{nV}/\sqrt{\text{Hz}}$
		$f = 1000\text{Hz}$	-	3.0	3.8	-	3.2	4.5	$\text{nV}/\sqrt{\text{Hz}}$
Input Noise Current Density (Note 5)	+25°C	$f = 10\text{Hz}$	-	1.7	4.0	-	1.7	-	$\text{pA}/\sqrt{\text{Hz}}$
		$f = 100\text{Hz}$	-	1.0	2.3	-	1.0	-	$\text{pA}/\sqrt{\text{Hz}}$
		$f = 1000\text{Hz}$	-	0.4	0.6	-	0.4	0.6	$\text{pA}/\sqrt{\text{Hz}}$
<b>TRANSFER CHARACTERISTICS</b>									
Large Signal Voltage Gain (Note 6)	+25°C	1000	1800	-	700	1500	-	V/mV	
	Full	600	1200	-	300	800	-	V/mV	
Common Mode Rejection Ratio (Note 7)	Full	114	126	-	100	120	-	dB	
Minimum Stable Gain	+25°C	1	-	-	1	-	-	V/V	
Unity-Gain-Bandwidth	+25°C	5	8.5	-	5	8.5	-	MHz	
<b>OUTPUT CHARACTERISTICS</b>									
Output Voltage Swing	+25°C	$R_L = 600\Omega$	$\pm 10.0$	$\pm 11.5$	-	$\pm 10.0$	$\pm 11.5$	-	V
		$R_L = 2\text{k}\Omega$	Full	$\pm 11.7$	$\pm 13.8$	-	$\pm 11.5$	$\pm 13.5$	-

## Specifications HA-5127, HA-5127A

**Electrical Specifications**  $V_+ = 15V, V_- = -15V, C_L < 50pF, R_S < 100\Omega$  (Continued)

PARAMETER	TEMP	HA-5127A			HA-5127			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
Full Power Bandwidth (Note 8)	+25°C	111	160	-	111	160	-	KHz
Output Resistance, Open Loop	+25°C	-	70	-	-	70	-	$\Omega$
Output Current	+25°C	16.5	25	-	16.5	25	-	mA
<b>TRANSIENT RESPONSE (Note 9)</b>								
Rise Time	+25°C	-	-	150	-	-	150	ns
Slew Rate (Note 11)	+25°C	7	10	-	7	10	-	V/ $\mu$ s
Settling Time (Note 10)	+25°C	-	1.5	-	-	1.5	-	$\mu$ s
Overshoot	+25°C	-	20	40	-	20	40	%
<b>POWER SUPPLY CHARACTERISTICS</b>								
Supply Current	+25°C	-	3.5	-	-	3.5	-	mA
	Full	-	-	4.0	-	-	4.0	mA
Power Supply Rejection Ratio (Note 12)	Full	-	2	4	-	16	51	$\mu$ V/V

**NOTES:**

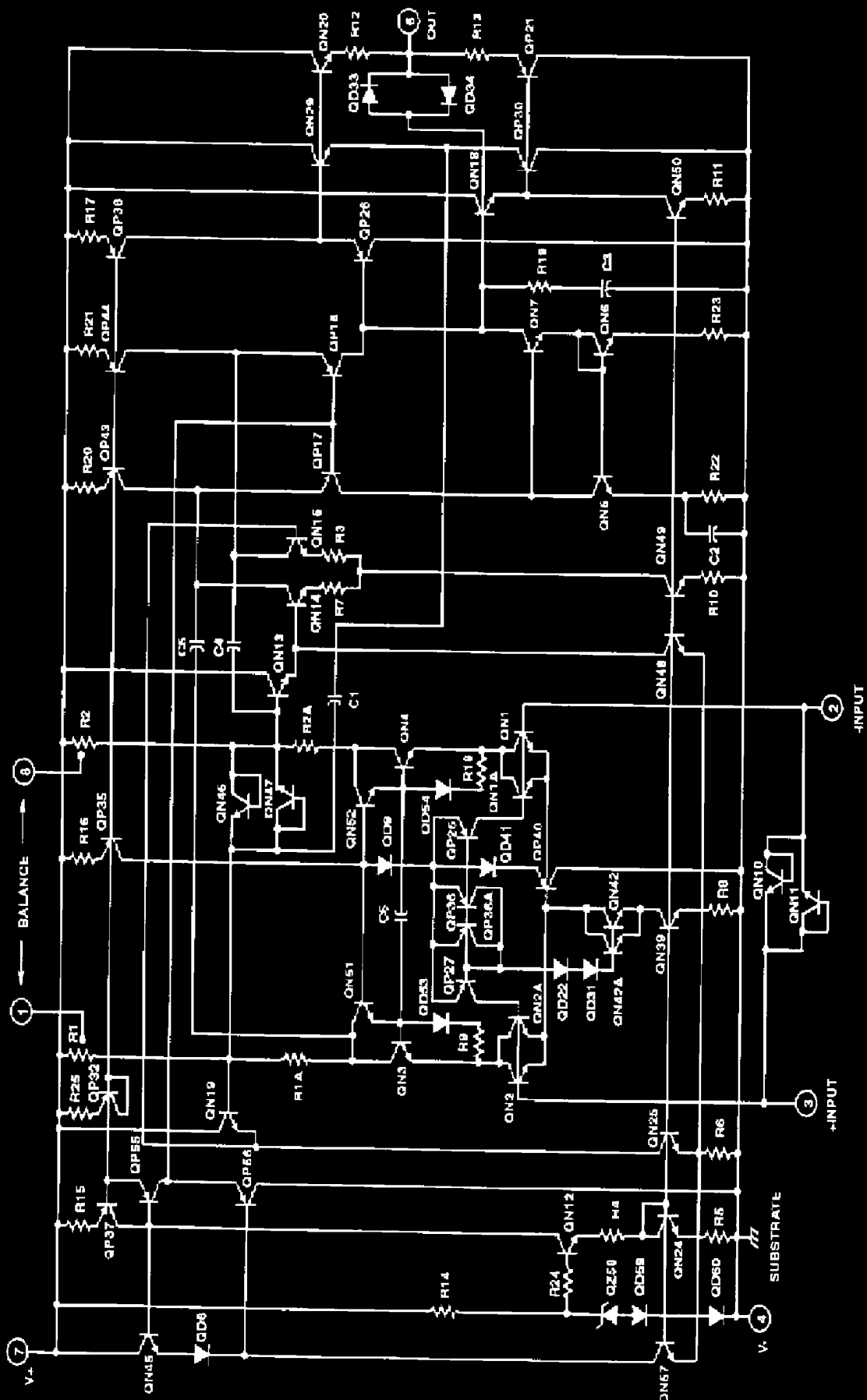
1. Absolute maximum ratings are limiting values, applied individually, beyond which the serviceability of the circuit may be impaired. Functional operability under any of these conditions is not necessarily implied.
2. For differential input voltages greater than 0.7V, the input current must be limited to 25mA to protect the back-to-back input diodes.
3. This parameter value is based upon design calculations.
4. Refer to Typical Performance section of the data sheet.
5. The limits for this parameter are guaranteed based on lab characterization, and reflect lot-to-lot variation.
6.  $V_{OUT} = \pm 10V, R_L = 2k\Omega$
7.  $V_{CM} = \pm 10V$
8. Full power bandwidth guaranteed based on slew rate measurement using:  $FPBW = \frac{\text{Slew Rate}}{2\pi V_{PEAK}}$ .
9. Refer to Test Circuits section of the data sheet.
10. Settling time is specified to 0.1% of final value for a 10V output step and  $A_V = -1$ .
11.  $V_{OUT} = 10V$  Step
12.  $V_S = \pm 4.5V$  to  $\pm 18V$
13. See Thermal Constants in "Die Characteristics" section.

### Die Characteristics

Transistor Count .....	63	Thermal Constants (°C/W)	$\theta_{JA}$	$\theta_{JC}$
Die Dimensions .....	65 x 104.3 x 19 mils (1700 $\mu$ m x 2600 $\mu$ m x 480 $\mu$ m)	Ceramic Mini-DIP .....	114	34
Substrate Potential* .....	V-	TO-99 Metal Can .....	108	33
Process .....	Bipolar-DI	Plastic DIP .....	92	30
		SOIC .....	157	43

\* The substrate may be left floating (Insulating Die Mount) or it may be mounted on a conductor at V- potential.

Schematic Diagram



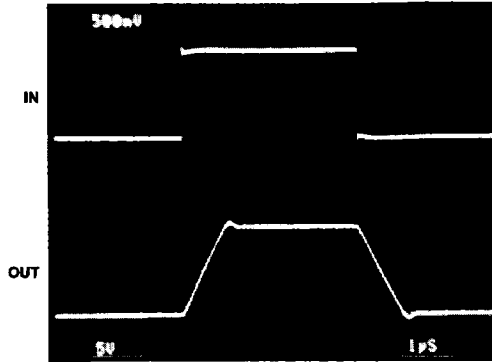
**Test Circuits**



FIGURE 1. LARGE AND SMALL SIGNAL RESPONSE TEST CIRCUITS

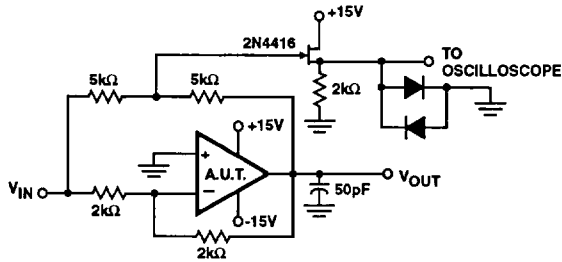
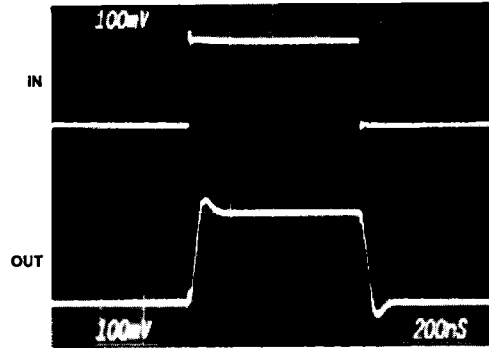
**LARGE SIGNAL RESPONSE**

Vertical Scale: (Volts: Input = 0.5V/Div.)  
 (Output = 5V/Div.)  
 Horizontal Scale: (Time = 1μs/Div.)



**SMALL SIGNAL RESPONSE**

Vertical Scale: (Volts: 100mV/Div.)  
 Horizontal Scale: (200ns/Div.)



- $A_v = -1$
- Feedback and summing resistors should be 0.1% matched.
- Clipping diodes are optional. HP5082-2810 recommended.

FIGURE 2. SETTLING TIME TEST CIRCUIT

**Typical Performance Curves** Unless Otherwise Specified:  $T_A = +25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$

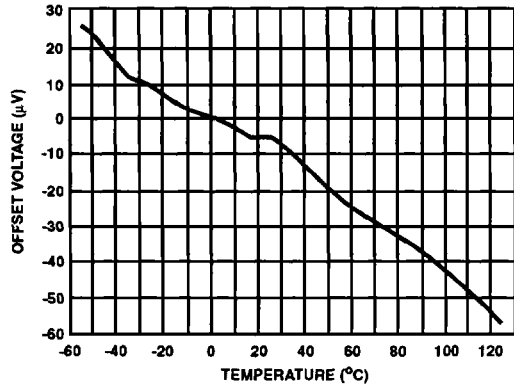


FIGURE 3. TYPICAL OFFSET VOLTAGE DRIFT vs TEMPERATURE

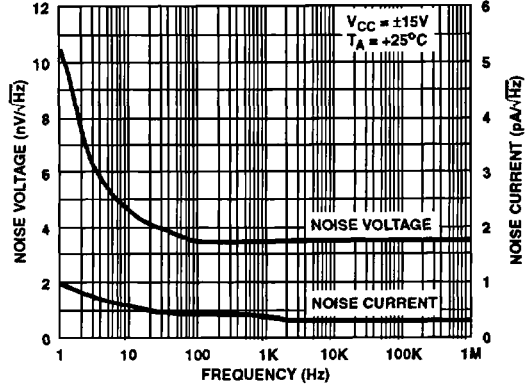


FIGURE 4. NOISE CHARACTERISTICS

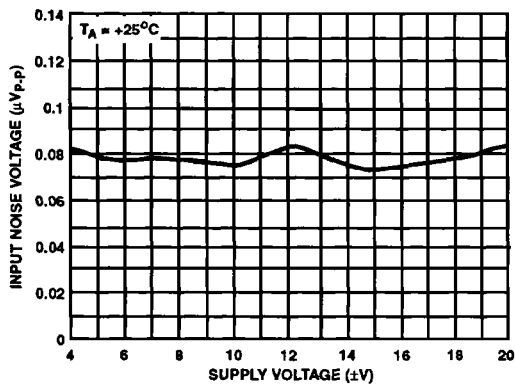


FIGURE 5. NOISE vs SUPPLY VOLTAGE

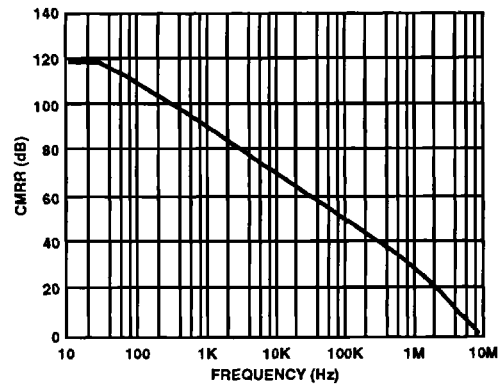


FIGURE 6. CMRR vs FREQUENCY

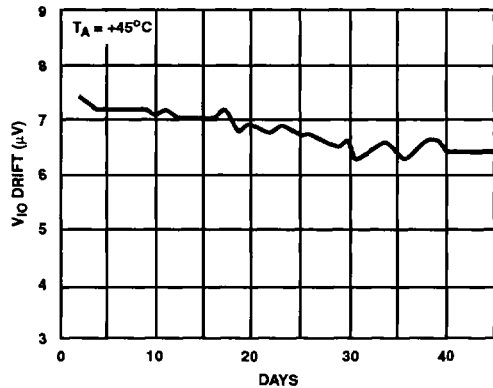


FIGURE 7. OFFSET VOLTAGE DRIFT vs TIME

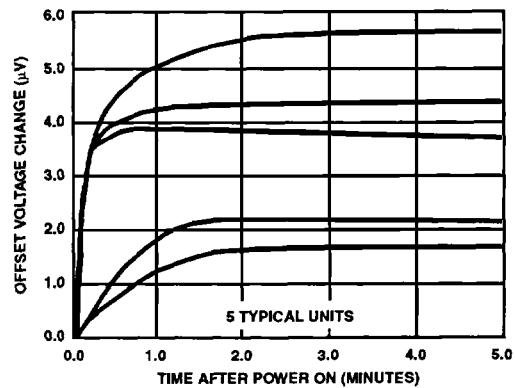


FIGURE 8. OFFSET VOLTAGE WARM UP DRIFT

**Typical Performance Curves** Unless Otherwise Specified:  $T_A = +25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$  (Continued)

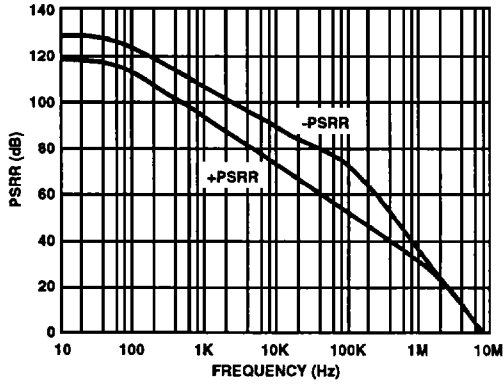


FIGURE 9. PSRR vs FREQUENCY

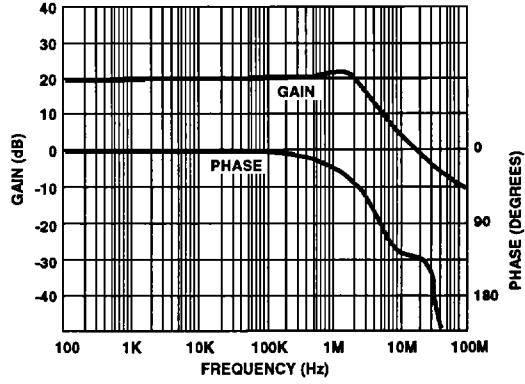


FIGURE 10. CLOSED LOOP GAIN AND PHASE vs FREQUENCY

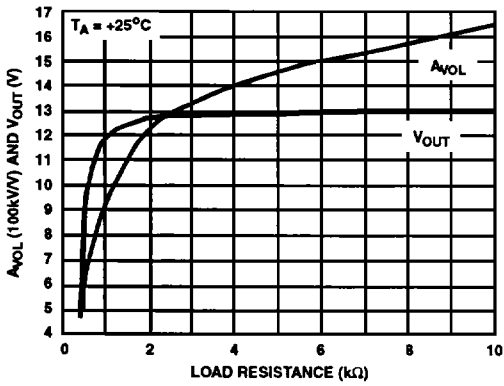


FIGURE 11.  $A_{\text{VOL}}$  AND  $V_{\text{OUT}}$  vs LOAD RESISTANCE

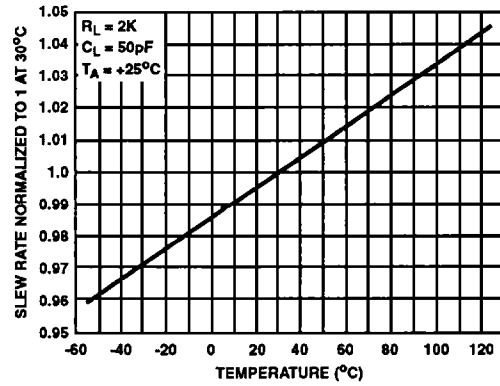


FIGURE 12. NORMALIZED SLEW RATE vs TEMPERATURE

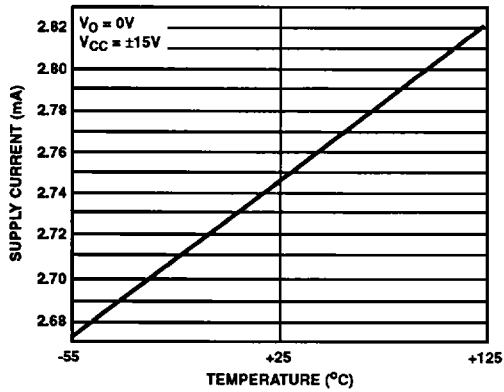


FIGURE 13. SUPPLY CURRENT vs TEMPERATURE

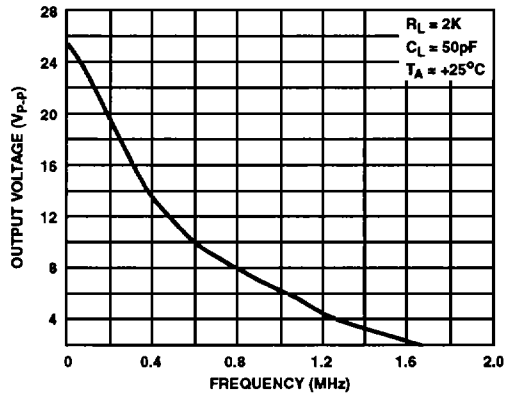


FIGURE 14. MAX UNDISTORTED SINEWAVE OUTPUT vs FREQUENCY

**Typical Performance Curves** Unless Otherwise Specified:  $T_A = +25^\circ\text{C}$ ,  $V_{\text{SUPPLY}} = \pm 15\text{V}$  (Continued)

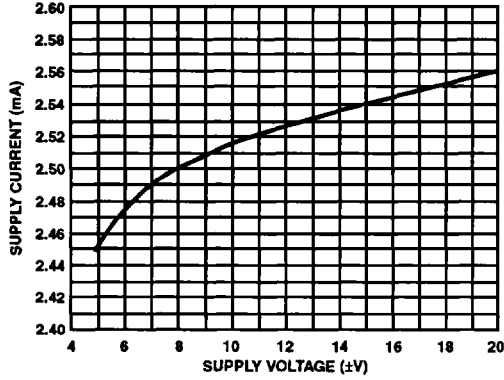


FIGURE 15. SUPPLY CURRENT vs SUPPLY VOLTAGE

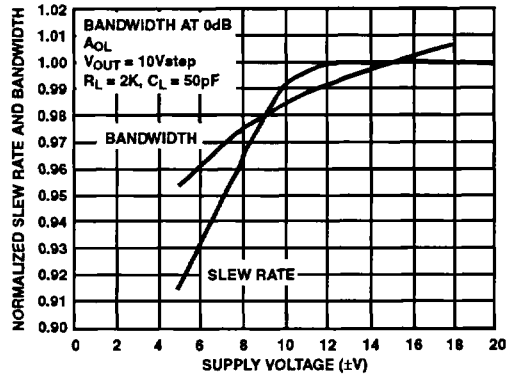


FIGURE 16. BANDWIDTH AND SLEW RATE vs SUPPLY VOLTAGE

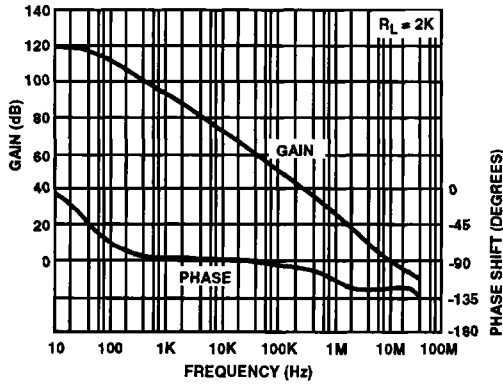


FIGURE 17. OPEN LOOP GAIN AND PHASE vs FREQUENCY

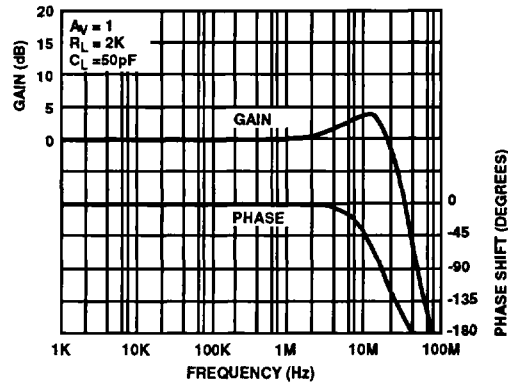


FIGURE 18. CLOSED LOOP GAIN AND PHASE vs FREQUENCY

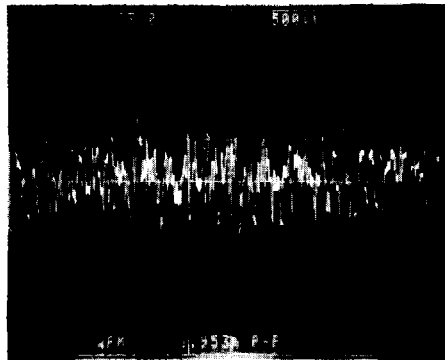
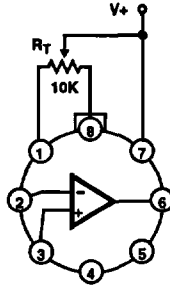


FIGURE 19. PEAK-TO-PEAK NOISE VOLTAGE (0.1Hz TO 10Hz)  
 Horizontal Scale = 1sec/Div.  
 Vertical Scale = 0.002 $\mu\text{V}$ /Div.  
 $A_{CL} = 25,000\text{V/V}$ ,  $E_N = 0.08\mu\text{V}_{p-p}$  RTI



**Application Information**



Tested Offset Adjustment Range is  $1V_{OS} + 1mV$  minimum referred to output. Typical range is  $\pm 4mV$  with  $R_T = 10k\Omega$ .

**FIGURE 20. SUGGESTED OFFSET VOLTAGE ADJUSTMENT**



Low resistances are preferred for low noise applications as a  $1k\Omega$  resistor has  $4nV/\sqrt{Hz}$  of thermal noise. Total resistances of greater than  $10k\Omega$  on either input can reduce stability. In most high resistance applications, a few picofarads of capacitance across the feedback resistor will improve stability.

**FIGURE 21. SUGGESTED STABILITY CIRCUITS**